

## ams 0.35 µ CMOS, HV CMOS & SIGE BICMOS MPW & SMALL VOLUME

EUROPRACTICE IC Service offers Multi-Project-Wafer (MPW) services and small volume production of ams in Europe.

## **Features and Benefits**

- Small minimum area pricing for academic customers
- Regularly scheduled MPW runs
- Flexible access to silicon capacity for small volumes
- World class mixed signal design kits hitkit
- C35B4Opto



C35	ams 0.35 µm CMOS with High Res Poly Resistor, highly linear PiP Capacitor, 3.3 V and 5 V operation, 17 KGates per mm <sup>2</sup> , EEPROM & OPTO option
S35	ams 0.35 $\mu m$ SiGe BiCMOS with HV SiGe Transistor option and $f_\text{T}$ of 60 GHz, MIM Capacitor, compatible with C35
LISE	ame 0.35 µm HV CMOS with 3 gate evides available 20 V 50 V and 120 V I DMOS devices

ams 0.35 µm HV CMOS with 3 gate oxides available, 20 V, 50 V and 120 V LDMOS devices, 4 operating voltages, isolated CMOS, low RDSon, compatible with C35, EEPROM option

Technology	H35	C35	S35
MPW Options	Gate Oxides: 3.3V, 5V & 20V, LDMOS to 120V, low RDSon, PiP Capacitor, 4 Metal (Al), Hi-Res Poly, Thick metal module	Gate Oxides: 3.3V & 5V, PiP Capacitor, 4 Metal (Al), Hi-Res Poly,  C35B4Opto: ARC or BARC, Photo Diodes	Gate Oxides: 3.3V & 5V, SiGe BiCMOS High- Speed and High-Voltage, PiP or MIM Capacitor, 4 Metal (AI), Hi-Res Poly, Thick metal module